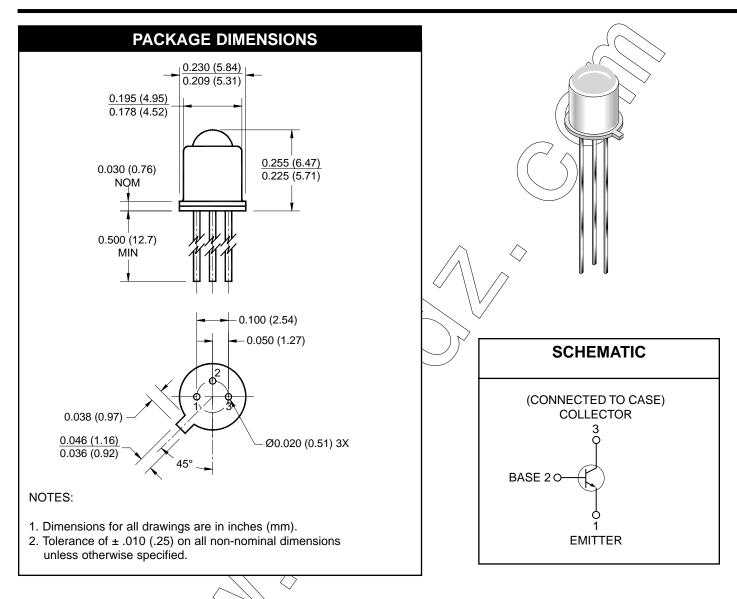
L14G1 L14G2 L14G3



DESCRIPTION

The L14G1/L14G2/L14G3 are silicon phototransistors mounted in a narrow angle, TO-18 package.

FEATURES

- · Hermetically sealed package
- Narrow reception angle



L14G1 L14G2 L14G3

| Parameter | Symbol | Rating | Unit |
|--|--------------------|----------------|------|
| Operating Temperature | T _{OPR} | -65 to +125 | °C |
| Storage Temperature | T _{STG} | -65 to +150 | °C |
| Soldering Temperature (Iron)(3,4,5 and 6) | T _{SOL-I} | 240 for 5 sec | °C |
| Soldering Temperature (Flow)(3,4 and 6) | T _{SOL-F} | 260 for 10 sec | °C |
| Collector to Emitter Breakdown Voltage | V _{CEO} | 45 | V |
| Collector to Base Breakdown Voltage | V _{CBO} | 45 | V |
| Emitter to Base Breakdwon Voltage | V _{EBO} | 5 | V |
| Power Dissipation (T _A = 25°C) ⁽¹⁾ | P _D | 300 | mW |
| Power Dissipation (T _C = 25°C) ⁽²⁾ | P _D | 600 | mW |

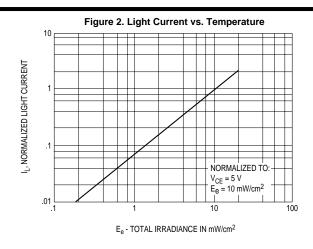
NOTE:

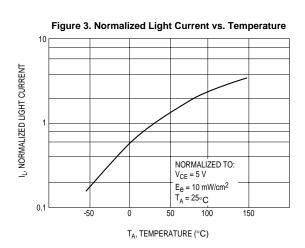
- 1. Derate power dissipation linearly 3.00 mW/°C above 25°C ambient.
- 2. Derate power dissipation linearly 6.00 mW/°C above 25°C case.
- 3. RMA flux is recommended.
- 4. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 5. Soldering iron tip 1/16" (1.6mm) minimum from housing.
- 6. As long as leads are not under any stress or spring tension.
- 7. Light source is a GaAs LED emitting light at a peak wavelength of 940 nm.
- 8. Figure 1 and figure 2 use light source of tungsten lamp at 2870°K color temperature. A GaAs source of 3.0 mW/cm² is approximately equivalent to a tungsten source, at 2870°K, of 10 mW/cm².

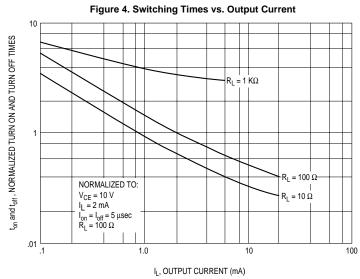
| ELECTRICAL / OPTICAL CHARACTERISTICS (TA =25°C) (All measurements made under pulse conditions) | | | | | | | | | |
|--|---|----------------------|-----|-----|------|---------|--|--|--|
| PARAMETER | TEST CONDITIONS | SYMBOL | MIN | TYP | MAX | UNITS | | | |
| Collector-Emitter Breakdown | $I_{\rm C} = 10 \text{ mA}, \text{ Ee} = 0$ | BV _{CEO} | 45 | | _ | V | | | |
| Emitter-Base Breakdown | $I_E = 100 \mu A, Ee = 0$ | BV _{EBO} | 5.0 | | _ | V | | | |
| Collector-Base Breakdown | $I_C = 100 \mu A, Ee = 0$ | BV _{CBO} | 45 | | _ | V | | | |
| Collector-Emitter Leakage | V _{CE} = 10 V, Ee = 0 | I _{CEO} | _ | | 100 | nA | | | |
| Reception Angle at 1/2 Sensitivity | | θ | | ±10 | | Degrees | | | |
| On-State Collector Current L14G1 | Ee = 0.5 mW/cm ² , $V_{CE} = 5 V^{(7,8)}$ | I _{C(ON)} | 1.0 | | _ | mA | | | |
| On-State Collector Current L14G2 | Ee = 0.5 mW/cm ² , $V_{CE} = 5 V^{(7,8)}$ | I _{C(ON)} | 0.5 | | | mA | | | |
| On-State Collector Current L14G3 | Ee = 0.5 mW/cm ² , $V_{CE} = 5 V^{(7,8)}$ | I _{C(ON)} | 2.0 | | | mA | | | |
| Turn-On Time | $I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V}, R_L = 100 \Omega$ | t _{on} | | 8 | | μs | | | |
| Turn-Off Time | I_C = 2 mA, V_{CC} = 10 V, R_L =100 Ω | t _{off} | | 7 | | μs | | | |
| Saturation Voltage | $I_C = 1.0 \text{ mA}, Ee = 3.0 \text{ mW/cm}^{2(7,8)}$ | V _{CE(SAT)} | _ | | 0.40 | V | | | |

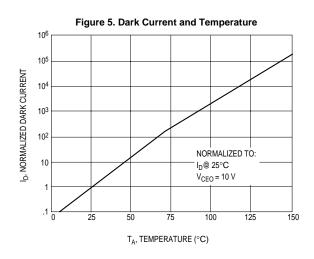


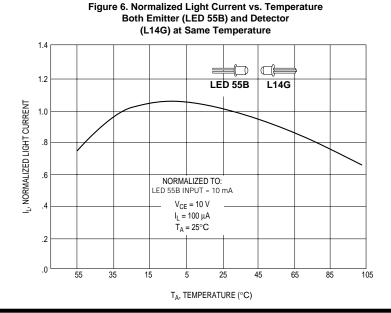
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L14G1 L14G2 L14G3

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